

<b>L Number</b>	<b>Hits</b>	<b>S arch T xt</b>	<b>DB</b>	<b>Time stamp</b>
-	16	(r pair).clm. and r pair.ab. and (tft or (thin near film near transistor)).clm. and channel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 15:58
-	5	(repair).clm. and repair.ab. and (tft or (thin near film near transistor)).clm. and channel.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 15:58
-	11	(repair near2 (electrode or line)).clm. and repair.ab. and (tft or (thin near film near transistor)).clm. and channel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 15:58
-	2	(repair near2 (electrode or line)).clm. and repair.ab. and (tft or (thin near film near transistor)).clm. and channel.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 15:59
-	4	(repair near2 (electrode or line)).clm. and (tft or (thin near film near transistor)).clm. and channel.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 15:59
-	28	(repair near2 (electrode or line)).clm. and (tft or (thin near film near transistor)).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 15:59
-	23	(repair near2 (electrode or line)).clm. and (tft or (thin near film near transistor)).clm. and repair.ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 16:00
-	4	(repair near2 (electrode)).clm. and (tft or (thin near film near transistor)).clm. and repair.ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 16:01
-	3	(repair near (electrode)).clm. and (tft or (thin near film near transistor)).clm. and repair.ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 16:01
-	5	(repair near (electrode)).clm. and (tft or (thin near film near transistor)).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 16:01

-	6	(r pair n ar (el ctr d )).clm. and (tft r (thin n ar film near transist r))	USPAT; US-P PUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 16:02
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